



Apropos 17

**Advanced Properties and Processes in
Optoelectronic Materials and Systems
30 September – 1 October, 2020**

Sattelite Event 
Lithuania-Poland Workshop
on Physics and Technology

CONFERENCE PROGRAMME

Center for Physical Sciences and Technology (FTMC), Vilnius, Lithuania
Venue: FTMC at Sunrise Valley, Saulėtekio Ave. 3, Vilnius, Lithuania

30 September		
8:00-9:00		REGISTRATION
9:00-9:15		CONFERENCE OPENING CEREMONY Gintaras Valušis Director of Center for Physical Sciences and Technology Chair of Apropos 17 conference
9:15-10:35		Section 1: Semiconductor nanostructures and advanced photonics systems Chair Prof. Carlito Jr. Salonga Ponseca
9:15-9:45	Inv 1	Linas Minkevičius (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Review of innovative diffractive elements for Terahertz imaging applications
9:45-10:15	Inv2	Ramūnas Aleksiejūnas (<i>Vilnius University, Lithuania</i>) Impact of alloy disorder induced localization on hole diffusion in highly excited c-plane and m-plane InGaN quantum wells
10:15-10:35	O1	Janusz Sadowski (<i>University of Warsaw, Institute of Physics, Warsaw, Poland, Linnaeus University, Sweden</i>) MoTe ₂ transition metal dichalcogenide grown by molecular beam epitaxy – polytypes, structural and electrical properties
10:35-11:00		Coffee break
11:00-13:00		Section 2: Nano and Biophotonics Chair Dr. Kaibo Zheng
11:00-11:30	Inv3	Šarūnas Meškiniš (<i>Kaunas University of Technology, Lithuania</i>) Direct synthesis of the graphene on Si(100) substrate for solar cell applications

11:30-12:00	Inv4	Dovydas Banevičius (<i>Vilnius University, Lithuania</i>) Naphthyridine-based deep-blue TADF OLEDs with low efficiency roll-off
12:00-12:20	O2	Rusnė Ivaškevičiūtė-Povilauskienė (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) All-optical modulation of graphene layers
12:20-12:40	O3	Lena Golubewa (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Raman spectroscopic investigation of multi-walled carbon nanotubes mediated neutrophil activation
12:40-13:00	O4	Adil Rehman (<i>Institute of High Pressure Physics, Warsaw, Poland</i>) Modulation of electrical and noise characteristics of carbon nanotubes based devices
13:00-14:00		Lunch
14:00-15:50		Special session: Ultrafast THz techniques Chair Dr. Ignas Grigelionis
14:00-14:30	Inv5	Carlito S. Ponseca, Jr. (<i>Linköping University, Sweden</i>) - Ultrafast transient spectroscopy of organic and hybrid solar cells
14:30-14:50	O5	Kaibo Zheng (<i>Lund University, Sweden, Technical University of Denmark, Danmark</i>) Ultrafast spectroscopy of Quantum dot solar cells
14:50-15:10	O6	Ričardas Norkus (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Terahertz emission from a bulk GaSe crystal excited by above-bandgap photons
15:10-15:30	O7	Daniil Pashnev (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Investigation of two-dimensional plasma resonances in grating-gated AlGaIn/GaN heterostructures by terahertz time domain spectroscopy
15:30-15:50	O8	Marek Maciaszek (<i>University of Warsaw, Poland</i>) On the origin of the 4.1 eV luminescence in hexagonal boron nitride
15:50-16:15		Coffee break
16:15-18:20		Section 1: Semiconductor nanostructures and advanced photonics systems Chair Prof. Šarūnas Meškiniis
16:15-16:45	Inv6	Tadas Malinauskas (<i>Vilnius University, Lithuania</i>) Remote epitaxy of GaN via Graphene
16:45-17:05	O9	Ivan Yahniuk (<i>Institute of High Pressure Physics, Warsaw, Poland</i>) Temperature- & Pressure-induced transitions in HgTe QWs
17:05-17:20	O10	Roman M. Balagula (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Annealing-induced reduction of strain in GaAs/GaNAs core-shell nanowires
17:20-17:40	O11	Andrea Zelioli (<i>University of Modena, Italia</i>) GaInAs/GaAs Quantum Structures For Near Infrared Vertical-External-Cavity Surface-Emitting Lasers
17:40-18:00	O12	Simona Pūkienė (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) A3-B5 QW structures for IR range optoelectronic devices
18:00-19:30		Poster session (18 posters) Coffee and Snaps

1 October		
9:00-11:00		Satellite Event: Lithuanian Polish Workshop Chair Prof. <i>Janusz Sadowski</i>
9:00-9:10		WORKSHOP OPENING CEREMONY Ambassador Urszula Doroszewska, Embassy of Poland Jerzy Łusakowski (Chair from Poland)
9:10-9:35	Inv7	Nerija Žurauskienė (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Magnetoresistance Relaxation Phenomena in Nanostructured Lanthanum Manganite Films
9:35-10:00	Inv8	Wojciech Pacuski (<i>University of Warsaw, Poland</i>) Narrow excitonic lines and large-scale homogeneity of transition metal dichalcogenides grown by MBE on hBN
10:00-10:20	O13	<u>Maksym Dub</u> (<i>Institute of High Pressure Physics, Warsaw, Poland</i>) Graphene gate GaN/AlGaN field effects transistors for THz detection
10:20-10:40	O14	<u>Maria Szoła</u> (<i>Institute of High Pressure Physics, Warsaw, Poland</i>) THz magnetospectroscopy of HgCdTe bulk crystals with different Cd content
10:40-11:00	O15	<u>Paweł Komorowski</u> (<i>Warsaw University of Technology, Poland</i>) Machine learning enhanced design of diffractive optical elements
11:00-11:25		Coffee break
11:25-13:05		Section 3: Ultrafast and THz phenomena Chair Dr. <i>Linas Minkevičius</i>
11:25-11:55	Inv9	Alvydas Lisauskas (<i>Vilnius University and Institute of High Pressure Physics, Warsaw, Poland</i>) THz detectors and sources fabricated with CMOS technologies
11:55-12:25	Inv10	Guillaume Ducournau (<i>Université Lille, France</i>) THz communications and advanced RF characterization enabled by THz photonics
12:25-12:45	O16	<u>Dmytro B. But</u> (<i>Institute of High Pressure Physics, Warsaw, Poland</i>) Antenna Characterization of Monolithically Integrated Detectors for 0.62 THz
12:45-13:05	O17	<u>Domas Jokubauskis</u> (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Phase contrast sub THz imaging and applications
13:05-14:00		Lunch
14:00-15:50		Section 3: Ultrafast and THz phenomena Chair Prof. <i>Alvydas Lisauskas</i>
14:00-14:30	Inv11	Vincas Tamošiūnas (<i>Center for Physical Sciences and Technology, Vilnius, Vilnius University, Lithuania</i>) Reflectance spectra of selective emitter solar cells in terahertz and sub-terahertz ranges
14:30-14:50	O18	<u>Dmitri V. Lioubtchenko</u> (<i>KTH Royal Institute of Technology, Stockholm, Sweden</i>) Effect of lengths, diameters, and density of silver nanowire layers on terahertz conductivity

14:50-15:10	O19	<u>Ieva Žičkienė</u> (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Terahertz radiation induced by surface ballistic photogalvanic effect in GaAs LIPSS structures
15:10-15:30	O20	<u>Pavlo Sai</u> (<i>Institute of High Pressure Physics, Warsaw, Warsaw University of Technology, Poland</i>) AlGaN/GaN dual grating gate structures investigated in high magnetic field
15:30-15:50	O21	<u>Vladislovas Čižas</u> (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Fractional frequencies in microwave response of GaAs/AlGaAs superlattices
15:50-16:15		Coffee break
16:15-17:35		Section 4: Organics for Optoelectronics Chair Dr. Prof. Nerija Žurauskienė
16:15-16:35	O22	<u>Yuri Svirko</u> (<i>University of Eastern Finland, Joensuu, Finland</i>) Light-induced currents and THz emission from graphene
16:35-16:55	O23	<u>Ernesta Pocevičiute</u> (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Studies of Receptor and Its Ligand Interaction Using FRET and TIRF Microscopy
16:55-17:15	O24	<u>Edvinas Navakauskas</u> (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Structure determination of HEWL protein aggregates at liquid interfaces
17:15-17:35	O25	<u>Wanessa Melo</u> (<i>Center for Physical Sciences and Technology, Vilnius, Lithuania</i>) Antimicrobial photodynamic therapy: an alternative to overcome the biofilm resistance
17:40		Closing Remarks